

Supporting Information

Effects of Mo/W codoping on the visible-light photocatalytic activity of monoclinic BiVO₄ within the GGA+ U framework

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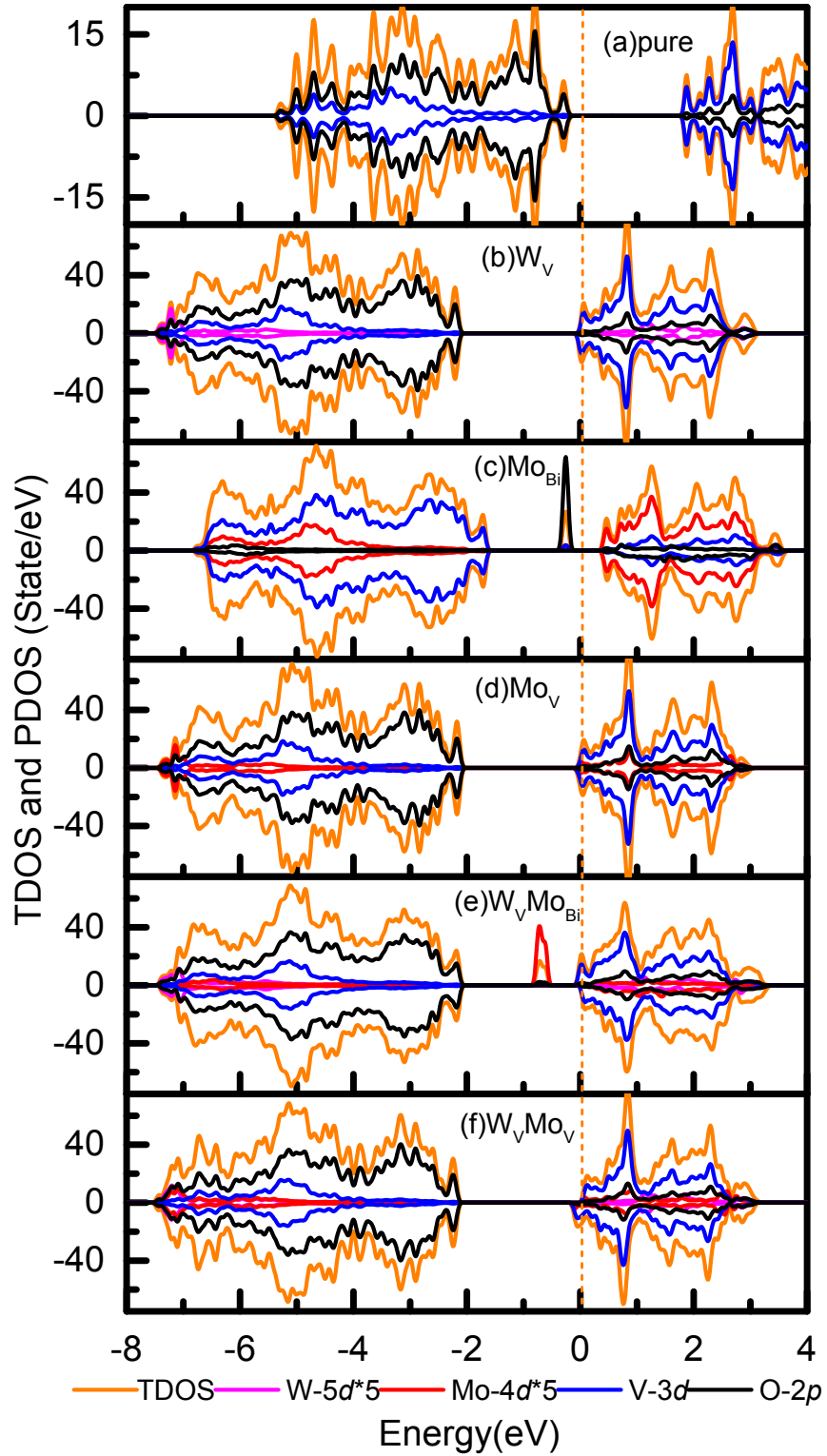


Fig. S1 DOS of pure, Mo,W mono-doped and Mo/W cod-oped BiVO_4 : (a)pure, (b) W_V , (c) Mo_{Bi} , (d) Mo_V , (e) $\text{W}_V\text{Mo}_{\text{Bi}}$ (f) W_VMo_V , from DFT calculations. The dashed lines stand for the Fermi level (at 0eV). The orange lines represent the total DOS (TDOS) black for O 2p, blue for V 3d, red for the quadruplicate of Mo 4d and magenta for the quadruplicate of W 5d, respectively. The Mo 4d and W 5d states are multiplied by 4 times to show their distribution clearly. The dashed lines stand for the Fermi level (at 0eV).

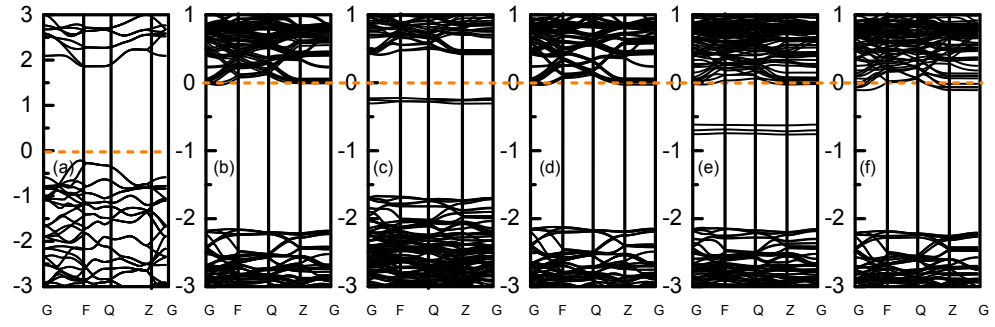


Fig. S2 Band structures of pure, Mo, W mono-doped and Mo/W co-doped BiVO_4 : (a) pure, (b) W_V , (c) Mo_{Bi} , (d) Mo_V , (e) $\text{W}_\text{V}\text{Mo}_{\text{Bi}}$ (f) $\text{W}_\text{V}\text{Mo}_\text{V}$, from DFT(GGA) calculations. The dashed lines stand for the Fermi level (at 0 eV).

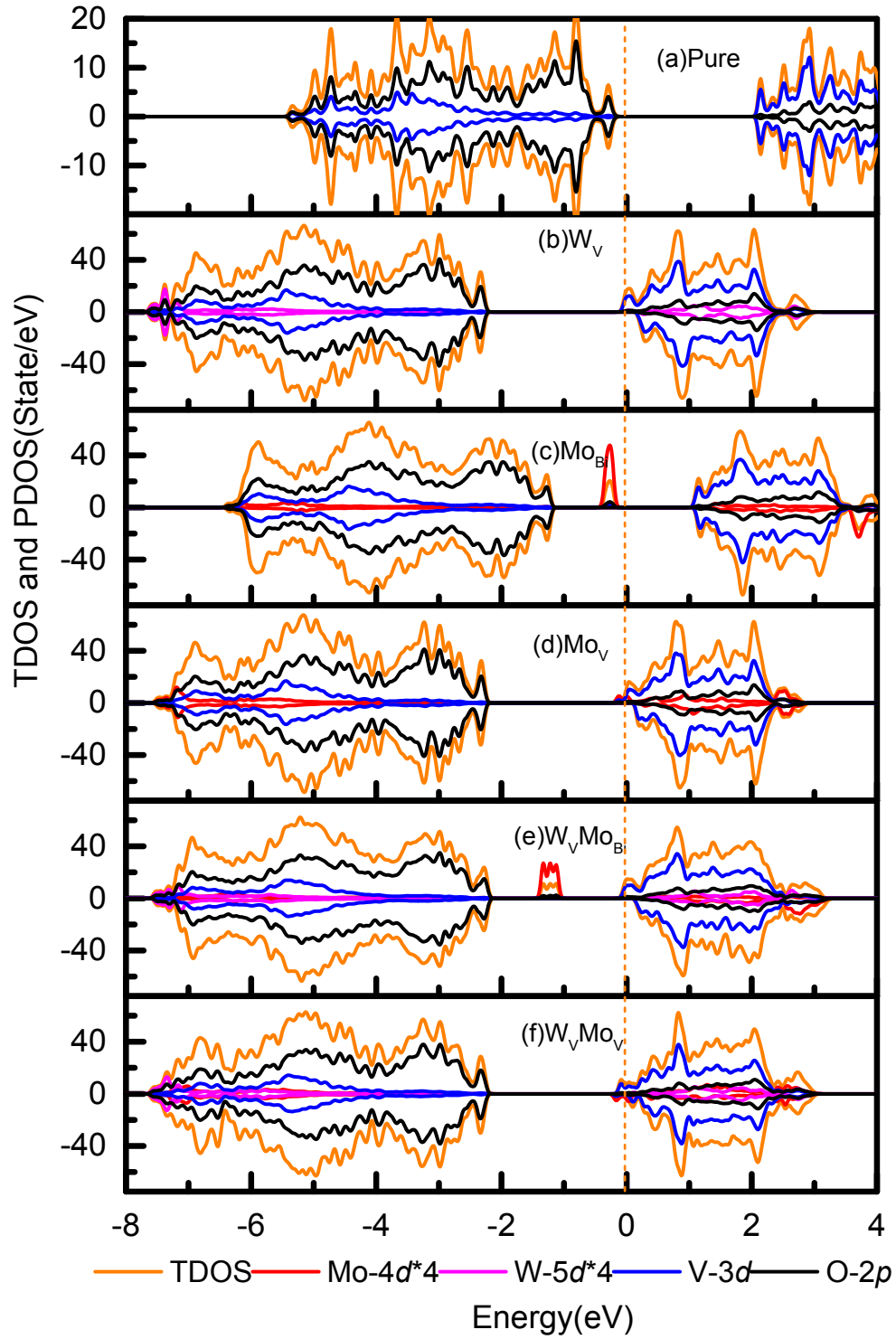


Fig. S3 DOS of pure, Mo,W mono-doped and Mo/W co-doped BiVO_4 : (a)pure, (b) W_V , (c) Mo_{Bi} , (d) Mo_V , (e) W_VMo_{Bi} (f) W_VMo_V , from DFT(GGA)+U calculations. The orange lines represent the total DOS (TDOS) black for O 2p, blue for V 3d, red for the quadruplicate of Mo 4d and magenta for the quadruplicate of W 5d, respectively. The Mo 4d and W 5d states are multiplied by 4 times to show their distribution clearly. The dashed lines stand for the Fermi level (at 0eV).

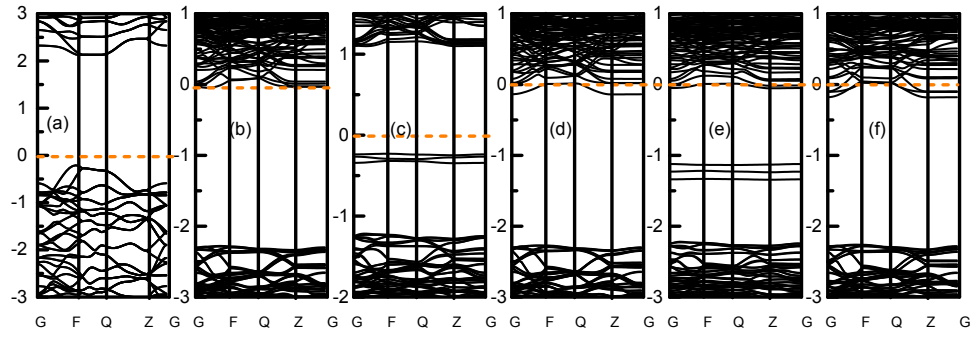


Fig. S4 Band structures of pure, Mo, W mono-doped and Mo/W co-doped BiVO_4 : (a) pure, (b) W_V , (c) Mo_Bi , (d) Mo_V , (e) $\text{W}_\text{V}\text{Mo}_\text{Bi}$ (f) $\text{W}_\text{V}\text{Mo}_\text{V}$, from DFT(GGA)+U calculations. The dashed lines stand for the Fermi level (at 0eV).

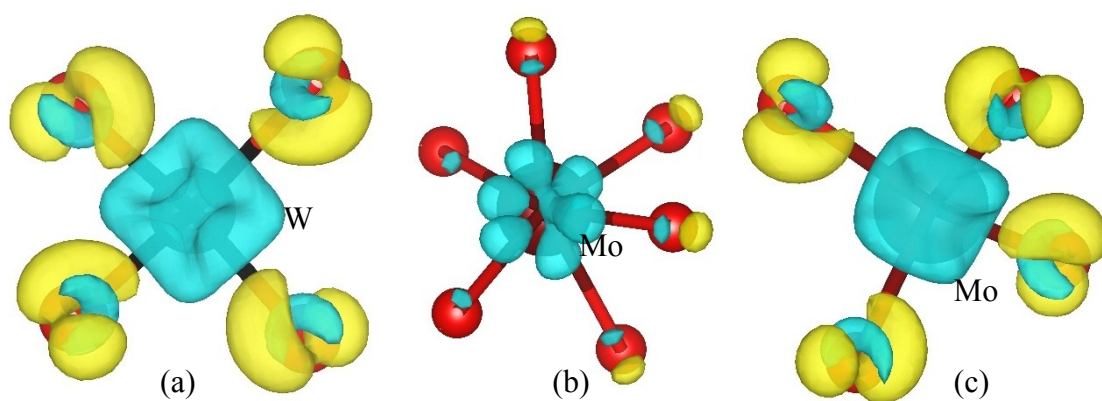


Fig S5 (Color online) Charge density difference isosurfaces of (a) W_V (b) Mo_Bi and (c) Mo_V monodoped BiVO_4 . The cyan region represents charge depletion and the yellow region represents charge accumulation. The isosurface value is $0.03 \text{ e}/\text{\AA}^3$. The light red, purple and black spheres represent O, Mo and W atoms, respectively.